

**Features:**

- 650V Schottky Diode
- Zero Reverse Recovery Current
- High Frequency Operation
- Positive Temperature Coefficient
- Temperature independent

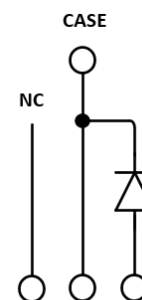
Switching

**Benefits:**

- Unipolar Rectifier
- Minimal switching loss
- Higher Efficiency
- Low cooling requirement

Symbol	Value	Unit
$V_{RRM}$	650	V
$I_F$ ( $T_c=152^\circ\text{C}$ )	15	A
$Q_C$	34	nC

**Outline**

**TO-247-3**
**Circuit**

**Applications:**

- Switch Mode Power Supply
- Booster diodes in PFC, DC/DC
- AC/DC converters

**Maximum Ratings**

Symbol	Parameter	Value	Unit	Test Conditions
$V_R$	DC Peak Reverse Voltage	650	V	$T_J = 25^\circ\text{C}$
$V_{RRM}$	Repetitive Peak Reverse	650	V	$T_J = 25^\circ\text{C}$
$V_{RSM}$	Surge Peak Reverse Voltage	650	V	$T_J = 25^\circ\text{C}$
$I_F$	Continuous Forward Current	47	A	$T_C = 25^\circ\text{C}$
		22		$T_C = 135^\circ\text{C}$
		15		$T_C = 152^\circ\text{C}$
$I_{FRM}$	Repetitive Peak Forward Surge Current	91	A	$T_C = 25^\circ\text{C}, T_p = 10\text{ms}, \text{Half Sine Wave}$
		81		$T_c = 110^\circ\text{C}, T_p = 10\text{ms}, \text{Half Sine Wave}$
$I_{FSM}$	Non-Repetitive Peak Forward Surge Current	120	A	$T_C = 25^\circ\text{C}, T_p = 10\text{ms}, \text{Half Sine Wave}$
		109		$T_c = 110^\circ\text{C}, T_p = 10\text{ms}, \text{Half Sine Wave}$
$P_D$	Power Dissipation	187	W	$T_C = 25^\circ\text{C}$
		62.5		$T_c = 125^\circ\text{C}$
$T_{J,max}$	Operating Junction Temperature	175	$^\circ\text{C}$	
$T_{stg}$	Storage Temperature Range	-55 to 175	$^\circ\text{C}$	

### Thermal characteristics

Symbol	Parameter	Min.	Typ.	Max.	Unit
$R_{thJC}$	Thermal resistance		0.80		$^{\circ}\text{C}/\text{W}$

### Electrical Characteristics

Symbol	Parameter	Value			Unit	Test Conditions
		Min.	Typ.	Max.		
$V_{DC}$	DC Blocking Voltage	650			V	$I_R = 100\mu\text{A}$ , $T_J = 25^{\circ}\text{C}$
$V_F$	Forward Voltage		1.45 1.8	1.7 2.1	V	$I_F = 15\text{A}$ , $T_J = 25^{\circ}\text{C}$ $I_F = 15\text{A}$ , $T_J = 175^{\circ}\text{C}$
$I_R$	Reverse Current		5 10	100 200	$\mu\text{A}$	$V_R = 650\text{V}$ , $T_J = 25^{\circ}\text{C}$ $V_R = 650\text{V}$ , $T_J = 175^{\circ}\text{C}$
$Q_C$	Total Capacitive Charge		34		nC	$I_F = 15\text{A}$ , $dI/dt = 350\text{A}/\mu\text{s}$ $T_J = 25^{\circ}\text{C}$ , $V_R = 400\text{V}$
$C$	Total Capacitance		644 88 85		pF	$V_R = 1\text{V}$ , $T_J = 25^{\circ}\text{C}$ , $f = 1\text{ MHz}$ $V_R = 200\text{V}$ , $T_J = 25^{\circ}\text{C}$ , $f = 1\text{ MHz}$ $V_R = 400\text{V}$ , $T_J = 25^{\circ}\text{C}$ , $f = 1\text{ MHz}$

### Typical Performance

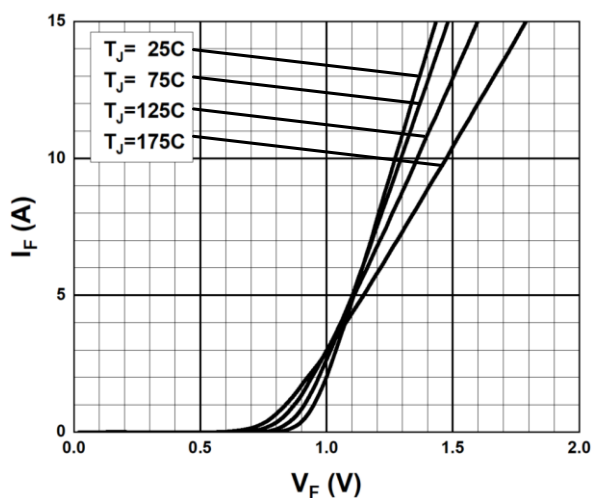


Fig. 1 Forward Characteristics

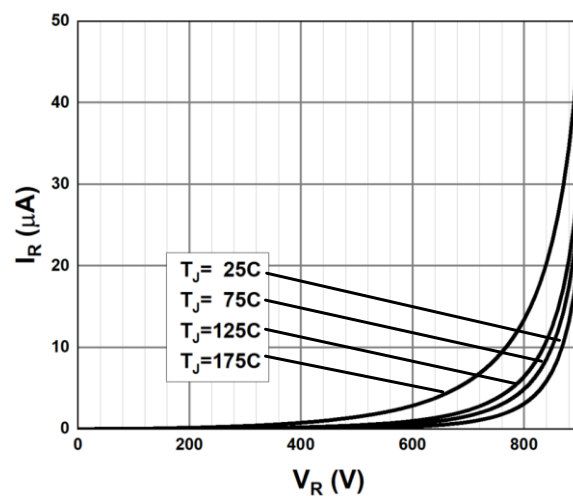
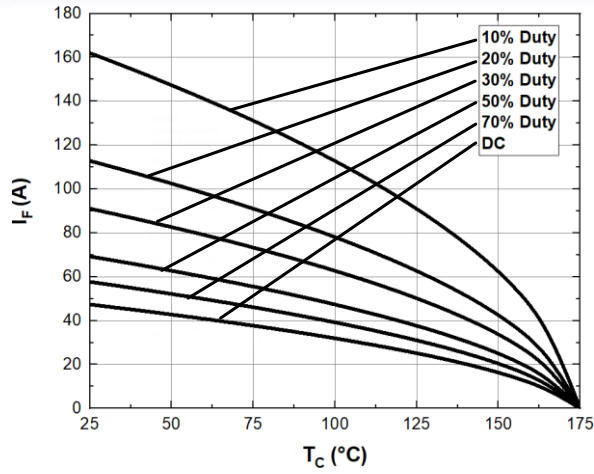
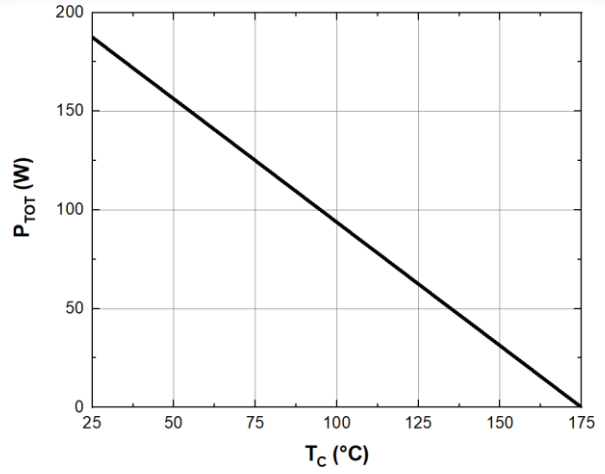


Fig. 2 Reverse Characteristics

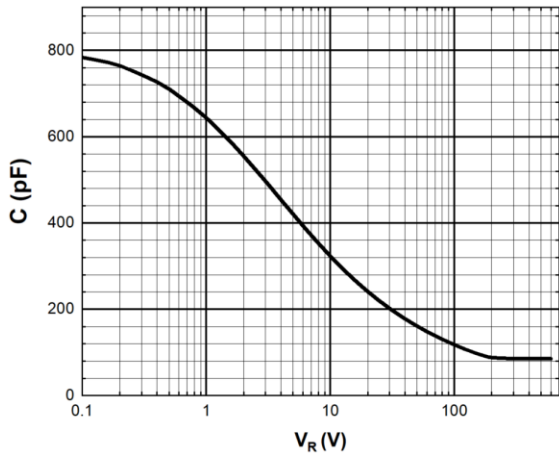
**Typical Performance**



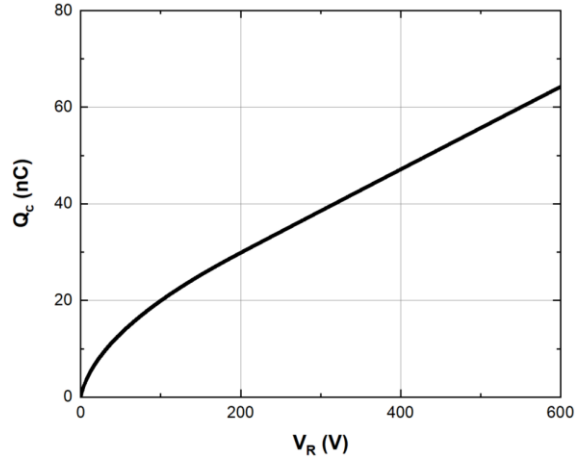
**Fig. 3 Current Derating**



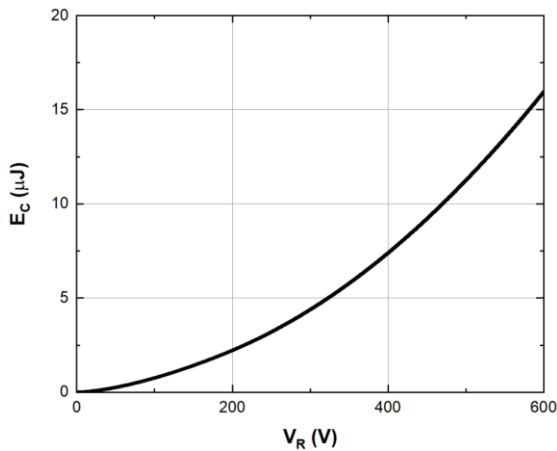
**Fig. 4 Power Derating**



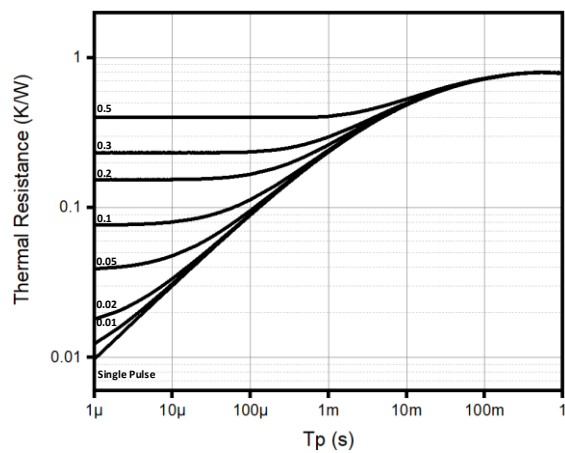
**Fig. 5 Capacitance vs. Reverse Voltage**



**Fig. 6 Recovery Charge vs. Reverse Voltage**

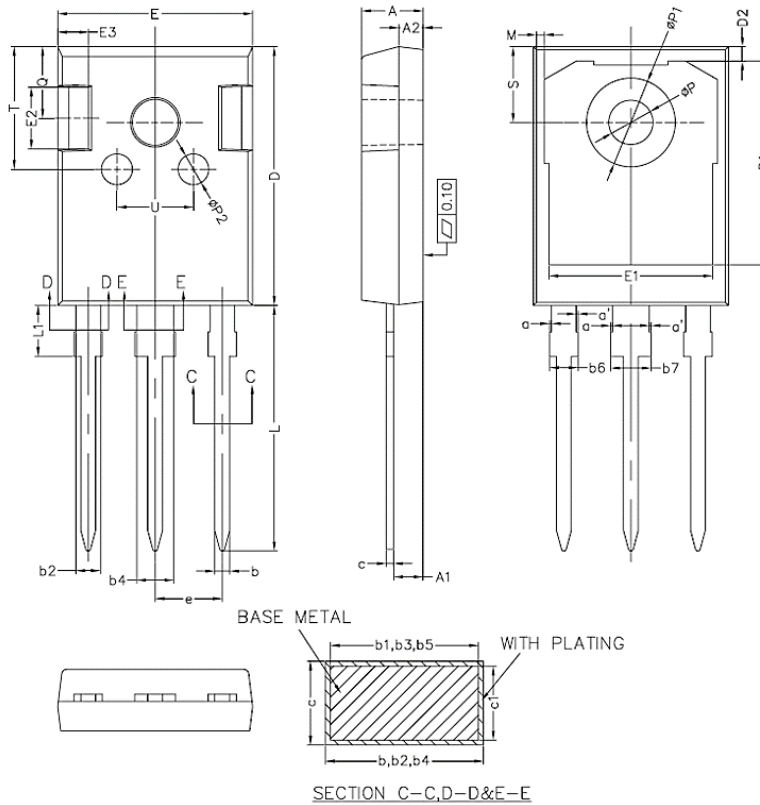


**Fig. 7 Capacitance stored Energy**



**Fig. 8 Thermal Impedance**

**Package TO-247-3 (Unit: mm)**



COMMON DIMENSIONS  
(UNITS OF MEASURE=MILLIMETER)

SYMBOL	MIN	NOM	MAX
A	4.90	5.00	5.10
A1	2.31	2.41	2.51
A2	1.90	2.00	2.10
a	0	—	0.15
a'	0	—	0.15
b	1.16	—	1.26
b1	1.15	1.2	1.22
b2	1.96	—	2.06
b3	1.95	2.00	2.02
b4	2.96	—	3.06
b5	2.95	3.00	3.02
b6	—	—	2.25
b7	—	—	3.25
c	0.59	—	0.66
c1	0.58	0.60	0.62
D	20.90	21.00	21.10
D1	16.25	16.55	16.85
D2	1.05	1.20	1.35
E	15.70	15.80	15.90
E1	13.10	13.30	13.50
E2	4.90	5.00	5.10
E3	2.40	2.50	2.60
e	5.34	5.44	5.54
L	19.80	19.92	20.10
L1	—	—	4.30
M	0.35	—	0.95
P	3.50	3.60	3.70
P1	7.00	—	7.40
P2	2.40	2.50	2.60
Q	5.60	—	6.00
S	6.05	6.15	6.25
T	9.80	—	10.20
U	6.00	—	6.40

NOTES:  
1. ALL DIMENSIONS REFER TO JEDEC STANDARD TO-247 AD DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS.  
2. EJECTION MARK DEPTH  $0.10^{+0.15}$ .

This Product has not been designed or tested for use in, and is not intended for use in, applications implanted into the human body nor in applications in which failure of the product could lead to death, personal injury or property damage, including but not limited to equipment used in the operation of nuclear facilities, life-support machines, systems, or air-traffic control systems.

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